INTRODUCTION

Tuning the bandgap of semiconductors via quantum size effects launched a technological revolution in optoelectronics, advancing solar cells (1,2), quantum dot light-emitting displays (3), and solid state lasers (4). Next-generation devices seek to use low-cost, easily processable semiconductors. A promising class of such materials is metal-halide perovskites (5), which currently propels research on emerging photovoltaics (6–8). Their narrowband emission permits very high color purity in light-emitting devices and vivid lifelike displays paired with low-temperature processing through printing-compatible methods (9–13). The success of perovskites in light-emitting devices is conditional upon finding reliable strategies to tune the bandgap while preserving good electrical transport. Thus far, color can be tuned chemically by mixed halide stoichiometry and by synthesis of colloidal nanoparticles (14, 15). Here, we introduce a general strategy of confining perovskite nanocrystallites (less than 10 nm) directly within device-relevant solid-state thin-film formats without the use of colloidal stabilization. With nanoporous alumina (npAAO) or nanoporous silicon (npSi) scaffolds serving as templates for the growth of perovskite nanocrystallites, we achieve fine-tuning of the bandgap across a wide color gamut from near-infrared (NIR) to ultraviolet (UV). Confinement in npSi facilitates a ~50-nm hypsochromic shift from green to blue photoluminescence (PL) for cesium-bromide perovskite nanocrystals. By infiltrating npAAO templates on transparent conductive substrates, we fabricate perovskite light-emitting diodes (LEDs) that achieve blue-shifted narrowband [full width at half maximum (FWHM), 17 nm] emission. Our demonstrations corroborate bandgap engineering through confinement in nanoporous solids as a powerful tool to precisely control the emission wavelength of perovskite nanocrystals in next-generation, solution-derived photonic sources.

Confining metal-halide perovskites in nanoporous thin films

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Controlling the size and shape of semiconducting nanocrystals advances optoelectronics and photonics. Quantum-confined, inexpensive, solution-derived metal halide perovskites offer narrowband, color-pure emitters as integral parts of next-generation displays and optoelectronic devices. We use nanoporous silicon and alumina thin films as templates for the growth of perovskite nanocrystallites directly within device-relevant architectures without the use of colloidal stabilization. We find significantly blue-shifted photoluminescence emission by reducing the pore size; normally infrared-emitting materials become visibly red, and green-emitting materials become cyan and blue. Confining perovskite nanocrystals within porous oxide thin films drastically increases photoluminescence stability because the templates auspiciously serve as encapsulation. We quantify the template-induced size of the perovskite crystals in nanoporous silicon with microfocus high-energy x-ray depth profiling in transmission geometry, verifying the growth of perovskite nanocrystallites throughout the entire thickness of the nanoporous films. Low-voltage electroluminescent diodes with narrow, blue-shifted emission fabricated from nanocrystalline perovskites grown in embedded nanoporous alumina thin films substantiate our general concept for next-generation photonic devices.
RESULTS

Nanoscale reactors concept

Here, we introduce solid-state nanoscale templating in a thin-film format to confine the growth of the perovskite directly within device-relevant architectures (Fig. 1A). This method yields perovskite nanocrystals with sizes of a few nanometers. We characterize nanocrystalline methylammonium lead trihalide (nCnMAPbX₃), with chloride, bromide, and iodide (X = Cl, Br, I) perovskites, as well as nanocrystalline cesium lead tribromide (nCsPbBr₃). We demonstrate the concept on two different nanoscaffold films, each with specific advantages. The first template comprises anodic aluminum oxide nanotubes (npAAO) with diameters of ~6 to 8 nm and lengths from 20 up to hundreds of nanometers. The second template is composed of an electrochemically etched npSi layer tens of micrometers thick renowned for its 3D spongy network of nanopores with tunable sizes ranging from 2 to 10 nm (31, 32). Both nanoscale solid-state scaffolds are prepared using scalable, room temperature anodization (detailed in Materials and Methods). The infiltrated pores serve as nanoreactors, constraining the growth of the perovskite crystals that form from the solution-borne precursors. We imaged ~150-nm-thick npAAO cross sections using scanning transmission electron microscopy (STEM) (Fig. 1B). The projection of the STEM image resolves both a network of perovskite nanocrystals partially filling the nanopores and the surrounding AAO matrix. Here, the nucleation density (resulting in the apparent nucleation profile) is controllable via the concentration of the precursor solution (see the Supplementary Materials). Exfoliated flakes of an npSi sponge filled with nanocrystals are shown in Fig. 1C. The perovskite nanocrystals appear dark (due to diffraction and mass contrast) in both matrices in these bright-field STEM (BF-STEM) images. We find blue-shifted PL in all cases; nanocrystalline methylammonium lead triiodide (nCnMAPbI₃) grown in npAAO blue-shifts by 62 nm, whereas nCnMAPbBr₃ and nCsPbBr₃ shift by 14 and 16 nm, respectively (Fig. 1D). Blue shifts in the PL are common in organic conjugated molecules when isolated (33, 34), for example, in solution or in npAAO (35–37) and silica (38, 39). In contrast, solid-state nanopore templating of nanocrystalline perovskites at sizes less than the exciton radius in the semiconductor (40) gives rise to strong quantum and dielectric confinement effects responsible for the observed blue-shifted emission. The npSi, featuring smaller pores than npAAO, affords shifts of up to 151 nm for nCnMAPbI₃ and ca. 50 nm for nCnMAPbBr₃ and nCsPbBr₃, and typically 15 nm for nCnMAPbCl₃ (Fig. 1E). These shifts correspond to significant bandgap changes of the perovskites of up to 0.37 eV for MAPbI₃, 0.25 eV for MAPbBr₃ and CsPbBr₃, and 0.11 eV for the already large bandgap MAPbCl₃. The magnitude of these shifts depends on the material, in line with the trend of the respective bandgap energies and the associated reduced exciton masses (15, 41). Our methods are not limited to single-halide precursors. Color tuning via a combination of size effects and adjusting halide compositional stoichiometry is possible in both npSi and npAAO (fig. S1), eventually allowing accessing the whole visible spectral range. The uniform blue-shifted emission of nanocrystalline perovskites in npAAO under UV illumination demonstrates that the whole sample area emits homogeneously over square centimeters (Fig. 1F). The blue shifts are even more pronounced for the npSi matrix; here, we achieve red emission (640 nm) from the NIR-emitting bulk MAPbI₃ and blue color (480 nm) from the normally green bulk CsPbBr₃ (Fig. 1G).

Color tunability

Precise nanopore-size tunability is a compelling advantage of the npSi system. We use a galvanostatic method (42) that allows pore size tuning by changing the anodization current density (detailed in Materials and Methods). The as-prepared porous silicon samples are hydride-terminated and weakly photoluminescent. We observed that a radiofrequency oxygen plasma treatment completely eliminates the PL of the porous silicon samples (fig. S2). This procedure accomplishes the dual role of extinguishing native luminescence and creating a surface that is highly wettable by the perovskite precursor solution. We find that the PL of MAPbI₃ becomes increasingly blue-shifted as the pore size is reduced, from an initial bulk-like NIR emission at 791 nm across the visible red range, with a maximal hypsochromic shift to 640 nm (Fig. 2A). MAPbBr₃ (Fig. 2B) and CsPbBr₃ (Fig. 2C) behave similarly; here, the normally green-emitting materials can be shifted to give visibly cyan (485 nm) and blue (479 nm) emission. In all these cases, the peak emission wavelength varies linearly with the anodization current used to prepare the pores (fig. S3), indicating a dependence of the bandgap on nanopore size. Even the emission of the wide-bandgap MAPbCl₃ can be shifted further into the UV range, well below 400 nm (Fig. 2D). Hypsochromic shifts obtained with transparent, thin-film npAAO templates on glass slides (250-nm npAAO; see Materials and Methods) are also shown (Fig. 2, A to C). The observed shifts qualitatively agree well with reported blue shifts for different methods of obtaining nanocrystals or nanoplatelets (20, 28). We find a PL quantum yield (PLQY) of up to 25% (x = 13.76%, α = 9.17%, n = 4) for nCnMAPbI₃, up to 60% (x = 36.04%, α = 16.23%, n = 4) for nCnMAPbBr₃, and up to 90% (x = 54.84%, α = 31.98%, n = 4) for nCsPbBr₃ in npAAO (see Materials and Methods for details). The PLQY of our nanoparticle emitters is significantly higher than what we observe for the bulk semiconductor films (<1 to 2%) and fits well within the range reported for other nanosized perovskite materials (27, 28, 30, 43). Time-resolved PL measurements (fig. S4) show a short lifetime for our nanocrystals (0.3 to 3 ns), whereas bulk films are longer-lived (3 to 25 ns). This behavior is known for quantum dot systems (15, 44) and also observed for MAPbI₃ films with varying crystalite dimensions (45) and for MAPbBr₃ in mesoporous silica (27).

Here, we show that the confinement effects enable broad tunability windows in emission color from single-halide precursors, leaving the spectral regions from 640 to 530 nm and from 479 to 405 nm unaddressed. To illustrate the generality of our approach, we complete these gaps by complementing the confinement effects with mixed halide stoichiometry. We demonstrate this with mixed iodide–bromide nanocrystals in npAAO, resulting in yellow emission, and with mixed bromide–chloride perovskites in npSi, resulting in deeper blue emission (fig. S1). Besides determining crystalite size, our thin-film oxide templates enhance the stability and largely prevent degradation of the nanocrystals when excited with blue light (405 nm) under ambient conditions. Whereas bulk films decay rather rapidly under these conditions, the PL intensity of nCnMAPbBr₃ in 250-nm-thick npAAO (Fig. 2E) initially increases by roughly 40% and then stabilizes without further changes in shape of the PL signal (Fig. 2F). Similar results are obtained when comparing CsPbBr₃ with nCnCsPbBr₃ (Fig. 2, G and H), wherein an initial increase is followed by a delayed decay back to the original values. We believe that the alumina matrix serves as an encapsulation that largely prevents ingress of oxygen and water. The initial increase in PL intensity may be attributed to light curing with oxygen, reducing nonradiative charge recombination by deactivating the respective trapping sites (46). Encapsulating nCnMAPbBr₃ and nCnCsPbBr₃ samples with epoxy and glass slides further corroborates these findings because the PL intensity remains essentially unchanged in the absence of oxygen and water. This in turn demonstrates the stability...
Fig. 1. Metal-halide perovskites confined in nanoporous films. (A) Schematic of nanoscale solid film templates (npAAO on the left and npSi on the right) infused with perovskite nanocrystals. The chemical structure of methylammonium lead trihalide (ncMAPbX₃) and cesium lead trihalide perovskites (ncCsPbX₃), with chloride, bromide, and iodide (X = Cl, Br, I), is shown in the middle. (B) BF-STEM image of a 170-nm-high, ~100-nm-thick npAAO filament, indicating alumina nanopores of 6 to 8 nm in diameter, partially filled with conjoined perovskite nanocrystals. (C) Exfoliated flake of npSi filled with MAPbI₃ imaged by BF-STEM. Perovskite nanocrystals appear dark because of their diffraction and mass contrast. Nanocrystals on the right appear aggregated; this is an imaging artefact caused by an increase in flake thickness. (D) PL of ncMAPbI₃ grown in npAAO (solid red line), blue-shifted by 62 nm. ncMAPbBr₃ (solid green line) and ncCsPbBr₃ (solid cyan line) are shifted by 14 and 16 nm, respectively. Dashed lines show bulk film PL. (E) PL of perovskite-infiltrated npSi. These smaller pores result in a 150-nm shift for ncMAPbI₃ (solid red line), 52 nm for ncMAPbBr₃ (solid cyan line), 51 nm for ncCsPbBr₃ (solid blue line), and 14 nm for ncMAPbCl₃ (solid purple line). Dashed lines indicate bulk film PL. (F and G) Photographs of square centimeter–scaled thin films of nanocrystalline perovskites under UV illumination: npAAO on glass slides (F) and npSi on Si wafers (G). The circular areas in (G) are nanoporous.
Fig. 2. PL tuning and stability of perovskites confined in nanoporous films. The dashed lines represent the bulk PL, whereas the dotted lines are the PL of perovskites in npAAO. Solid lines correspond to the PL of perovskites grown in npSi, with successive blue-shifted peaks originating from samples with progressively smaller pore sizes. (A) MAPbI$_3$ bulk versus crystals confined in npAAO and six differently sized npSi scaffolds, showing the transition from NIR emission to visible red is observed. (B) MAPbBr$_3$ bulk versus crystals confined in npAAO and eight differently sized npSi scaffolds, showing emission shifting from green to blue. (C) CsPbBr$_3$ bulk versus confined nanocrystals in the same set of npAAO and npSi. (D) The UV-emitting MAPbCl$_3$ bulk compared with confined crystals in two of the smallest npSi matrices. Even this already wide-bandgap material can be blue-shifted via spatial confinement to emit below 400 nm. (E) Time evolution of the PL intensity during illumination at 405 nm under ambient conditions for ncMAPbBr$_3$ in npAAO (cyan empty circles) compared to bulk planar films of MAPbBr$_3$ on glass (green empty squares), evidencing encapsulation-like effects of the npAAO thin film. Sealing ncMAPbBr$_3$ samples with epoxy and glass slides (dark blue empty triangles) results in an essentially constant PL signal, demonstrating stability under continuous illumination without light-induced degradation. (F) PL signal for ncMAPbBr$_3$ in npAAO after 1-min (dark green), 30-min (green), and 1-day (light green) illumination at 405 nm. (G) Time evolution of the PL intensity during illumination at 405 nm under ambient conditions for ncCsPbBr$_3$ in npAAO (blue empty circles) and bulk CsPbBr$_3$ on glass (cyan empty squares). Epox- and glass-encapsulated ncCsPbBr$_3$ samples (dark blue empty triangles) again show stable PL and no photodegradation. (H) PL signal for ncCsPbBr$_3$ in npAAO after 1-min (light blue), 30-min (blue), and 1-day (dark blue) illumination at 405 nm.
of our nanocrystals under photoexcitation, without signs for light-induced degradation.

**Size analysis**
To investigate whether the observed hypsochromic shifts are size-induced, we perform structural studies. Electron microscopy is used to test for the porosity and nucleation profile, as well as to get a first indication about particle sizes. We prepare focused ion beam (FIB)–milled lamellae of npAAO and find columnar structures on large areas using BF-STEM (fig. S5). From the uniform distribution of nanopores (top-view SEM; fig. S5), we estimate a template porosity of 15%. Energy-dispersive x-ray spectroscopy (EDX) scans confirm infiltration of the npAAO with perovskite nanocrystals (fig. S5). The EDX analysis also confirms that the bright regions (due to z-contrast) imaged on exfoliated npSi/ncMAPbI3 flakes in high-angle annular dark field (HAADF) (fig. 3A) are perovskites. EDX line scans (Pb L line) from the thinnest parts of the flakes allow us to infer a size of ~4 nm for the perovskite crystals (Fig. 3B). To quantitate the size of the perovskite crystallites that form in npSi, we use microfocus high-energy x-ray depth profiling in transmission geometry (fig. S6). Three npSi/ncMAPbI3 samples (anodized at 15, 25, and 30 mA cm\(^{-2}\)) are probed to correlate the anodization current density with the resulting crystal size. The microfocus beam (FWHM, 2 to 5 μm; compare figs. S6 and S7) allows us to verify the formation of perovskite nanocrystals throughout the entire thickness of the npSi layers. The obtained diffraction patterns (figs. S6 and S7) are a superposition of the background due to the npSi and debye rings of the perovskite crystallites within the pores. The background-corrected azimuthally averaged MAPbI\(_3\) scattering signal is extracted as a function of the scattering vector \(q\). The maximal perovskite signal for each sample is shown in Fig. 3C (for intensity profiles at all depths, see figs. S6 (30 mA cm\(^{-2}\)) and S7 (15 and 25 mA cm\(^{-2}\))). The observed peak positions obtained from the debye rings are indexed to a tetragonal structure with the lattice constants \(a = b = 8.90(3)\) Å and \(c = 12.71(5)\) Å. These lattice constants match the literature values of Stoumpos et al. (47), \(a = b = 8.849(2)\) Å and \(c = 12.642(2)\) Å within 0.6%. A complete peak indexing is given in fig. S6. All MAPbI\(_3\) peaks show strong broadening due to finite crystal size. Using the Scherrer equation (48), we calculate the depth-dependent crystallite size (fig. 3, D to F) from the FWHM of the diffraction peaks (see figs. S6 and S7 for details). The amount of perovskite material accumulating at a specific depth can be read off from the depth-dependent diffracted power, that is, the integrated intensity of the perovskite diffraction peaks. In all cases, we find a rather narrow distribution of crystallite size versus depth, allowing us to average over the whole layer thickness using the amount of MAPbI\(_3\) at a specific depth as weights. We obtain average MAPbI\(_3\) crystallite sizes of 1.8, 2.1, and 4.5 nm for 15–, 25–, and 30–mA cm\(^{-2}\) npSi, respectively. This is the same order of magnitude as reported for the exciton Bohr radius in MAPbI\(_3\) (2.2 and 2.8 nm) (49, 50), accounting for the strongly blue-shifted emission observed in these nanocrystals. We further estimate the pore size and porosity of a 15–mA cm\(^{-2}\) npSi scaffold from additional x-ray experiments (fig. S8). A film porosity of 57% is determined from x-ray transmission measurements. Small-angle x-ray scattering (SAXS) experiments following the method of Porod (51) reveal an average pore diameter of 4.0 nm. Comparing this with the crystal size analysis, we find that the formed perovskite nanocrystals are smaller than the surrounding pores (1.8 nm versus 4.0 nm). This indicates that the pores act as weakly connected nanoreactors, placing an upper bound on the perovskite nanocrystal size. Because of this enhancement of confinement, nanocrystals consist-

**Light-emitting diodes**
Incorporating nanoscale (less than 10 nm) perovskite emitters as active layers in LEDs is currently pursued with colloidal dots and platelets, promising low-cost high–color purity photonic sources (9–11, 52–55). The possibility and ease of 3D structuring incorporated in thin-film device architectures are unique benefits of our nanoporous solid templates. Translating this concept of solid-state confinement into devices requires electrical addressability of the nanotemplates. We demonstrate that insulating npAAO filled with perovskite aids the formation of conductive nanostructures, enabling low-voltage electroluminescent diodes (Fig. 4A) with narrow and blue-shifted emission. To fabricate nanoporous perovskite nanocrystal LEDs (npPeLEDs), a bilayer of Ti and Al is deposited onto transparent fluorine-doped tin oxide (FTO). Aluminum is anodized by electrochemical oxidation to obtain npAAO (60-nm film; Fig. 4B and fig. S9) and then infused with precursor solution to yield perovskite nanocrystals. We observe uniform PL over large areas after the npAAO is filled with perovskites from the solution (Fig. 4C), indicating the suitability of the titania/npAAO/perovskite composite films for diodes. Titanium is not porosified by the electrolyte during anodization, forming compact TiO\(_2\) that acts as the electron injection layer in the sandwich structure. The device is completed by a hole-conducting polymer (HTL) top layer and MoO\(_3/Ag\) contacts (Fig. 4A). Devices prepared with ncMAPbI\(_3\) give red electroluminescence (EL) peaking at 731 nm (Fig. 4D), that is, ~60 nm blue-shifted from the NIR emitting bulk. For CsPbBr\(_3\) devices, we find a sharp green-cyan EL centered at 518 nm. Its FWHM of 17 nm (Fig. 4E) is in line with the results of Li et al. (53) shown for CsPbBr\(_3\) nanocrystal devices. The diodes turn on at ~2.5 V and give about 300 cd m\(^{-2}\) operating at 5 V (Fig. 4F). At this voltage, the \(J-V\) (current density–voltage) characteristics show that npAAO/perovskite layers carry a current density of about 420 mA cm\(^{-2}\). Our perovskite LEDs have a current efficiency of ~0.09 cd A\(^{-1}\) and an external quantum efficiency of ~0.03%; however, the demonstrated PLQY of up to 90% for our perovskite nanocrystals suggests that higher efficiencies are achievable through further device optimization. This is expected to match the performance of current state-of-the-art 2D- and 3D-based perovskite LEDs (10, 13, 43, 52, 53, 55) while preserving the ease of color tuning. Control samples prepared without perovskite were electrically insulating. The optoelectronic quality of the composite nanoporous layer is exemplified by uniform EL over continuous areas as large as 15 mm\(^2\) (Fig. 4G).

**DISCUSSION**
We demonstrated blue emission from ncCsPbBr\(_3\) in npSi and cyan EL in npAAO-based LEDs. Strong blue shifts were observed for the silicon-based templates because their small pore sizes allow for crystallite sizes as small as 2 nm. Future electrical addressing of these templates seems feasible through down-scaling of the npSi matrix to sub–100-nm thicknesses via advanced silicon patterning or porosification protocols. Reducing the pore size in npAAO is expected to result in more pronounced blue shifts; feasible routes for this are optimization
**Fig. 3. Depth-resolved structural characterization of perovskite nanocrystals in npSi films.**

(A) HAADF-STEM image of an exfoliated npSi/ncMAPbI\(_3\) flake. The bright regions correspond to perovskite (due to z-contrast), as confirmed by EDX analysis. The Pb signal is plotted as orange overlay. (B) EDX line scan (Pb L line) of a single crystallite from the thinnest part of the flake [indicated as red line in (A)]. We find a crystallite size of 4 nm for 30–mA cm\(^{-2}\) npSi. (C) Background corrected, azimuthally averaged x-ray diffraction profiles of MAPbI\(_3\) in 30–mA cm\(^{-2}\) npSi (violet line), in 25–mA cm\(^{-2}\) npSi (blue line), and in 15–mA cm\(^{-2}\) npSi (green line) as a function of the scattering vector \(q\). The curves are normalized and vertically shifted for clarity. The log-scale highlights the increasing broadening of all MAPbI\(_3\) peaks with decreasing current density due to crystallite size reduction, suggesting increasingly strong confinement. The peaks are indexed to a tetragonal structure with the lattice constants \(a = b = 8.90(3) \text{ Å}\) and \(c = 12.71(5) \text{ Å}\). (D to F) Crystallite size and diffracted power of the MAPbI\(_3\) signal as function of depth for (D) 30–mA cm\(^{-2}\) npSi/ncMAPbI\(_3\), (E) 25–mA cm\(^{-2}\) npSi/ncMAPbI\(_3\), and (F) 15–mA cm\(^{-2}\) npSi/ncMAPbI\(_3\). Red circles: Depth-dependent crystallite size. Black line: Integrated intensity of the perovskite diffraction signal as a measure for the amount of perovskite at a specific depth. Dashed red line: Weighted average of the crystallite size. Error bars correspond to the 1-s values of the uncertainty resulting from data analysis and the initial resolution of the experiment. (G) PL peak emission energy against the average size of crystallites formed in three npSi layers prepared with indicated anodization current density. Error bars correspond to the SD of the crystallite size.
of the anodization protocol or narrowing the pore diameter by deposition of conformal interlayers, for example, via atomic layer deposition. The electrical performance of our npPeLEDs is expected to further improve by reducing nonradiative recombination within the semiconductor and at the TiO₂/perovskite and perovskite/HTL interfaces or by reducing exciton quenching inside the emitting layer. The npPeLEDs presented here already reached indoor-display brightness levels, demonstrating the potential of solid-state confinement for perovskite photonic sources. Color tuning in single-halide perovskites through quantum size effects may alleviate stability issues (56). Forming ligand-capped 2D or 3D nanocrystals directly within our nanoporous solids may open additional routes toward size and shape control in integrated, device-compatible thin-film structures. Future work should focus on fundamental research, exploring complex lateral and depth-resolved nanostructuring for manipulation of optoelectronic properties. Potential applications range from photon detectors and (polarized) electroluminescent devices to single-photon sources and metasurfaces.

Fig. 4. Perovskite-infused nanoporous thin films for LEDs. (A) Schematic of npPeLEDs. Devices are fabricated on glass/FTO by anodizing a titanium/aluminum bilayer. This electrochemical procedure produces npAAO with compact TiO₂ below. Precursor solution infused to the top of the pores yields conducting and electroluminescent nanocrystalline perovskite domains. A polymeric HTL and hole-injecting contact of MoOₓ/Ag complete the device stack. (B) SEM of anodized Ti/Al, showing the npAAO layer with pores of ~6-nm diameter on top of the scale-like Ti/TiO₂ domains below. (C) PL micrograph image taken of a Ti/npAAO layer infused with CsPbBr₃, evidencing uniform light emission across large areas of the sample. Excitation filter, 465 to 495 nm; barrier filter, 515 to 555 nm. (D) EL of an ncMAPbI₃ diode, (filled curve) centered around 731 nm, with bulk PL emission (dashed line) and PL of the ncMAPbI₃ diode (solid curve) plotted for comparison. (E) EL (filled curve) of an ncCsPbBr₃ diode with PL emission of the bulk (dashed line) and the ncCsPbBr₃ diode is shown (solid line). Cyan-green narrowband EL peaking at 518 nm is observed. (F) J-V characteristic of an ncCsPbBr₃ diode (black trace) plotted together with luminance (cyan). Devices turn on at ~2.5 V with a luminance of ~330 cd m⁻² at 5 V. (G) Photograph of a CsPbBr₃ diode while operating at 4 V, displaying cyan-green EL over the entire area of the pixel (15 mm²).

**MATERIALS AND METHODS**

**Perovskite precursor solutions**

All chemicals and solvents were purchased from commercial suppliers and used as received, if not stated otherwise. Methylammonium bromide (MABr) was synthesized from methylamine [33 weight % (wt %) in absolute ethanol; Sigma-Aldrich] and hydrobromic acid (48 wt %, aqueous; Sigma-Aldrich) and purified using diethylether (VWR) and absolute ethanol (Merck Millipore). Lead bromide (PbBr$_2$; 99.999%), dimethyl sulfoxide (DMSO; ≥99%), and methylammonium iodide (MAI) were supplied by Sigma-Aldrich, Merck Millipore, and Dyesol, respectively. Lead iodide (PbI$_2$; 99.9985%), cesium bromide (CsBr; 99.999%), and dimethyl formamide (DMF; 99.8%) were purchased from Alfa Aesar. All parent solutions were passed through polytetrafluoroethylene syringe filters (0.45 μm; Whatman). For MAPbI$_3$, PbI$_2$ (922 mg, 2.00 mmol), MAI (334 mg, 2.10 mmol), and DMF (2.25 ml) were mixed to yield a clear yellow solution. For MAPbBr$_3$, PbBr$_2$ (368 mg, 1.00 mmol), MABr (124 mg, 1.11 mmol), and DMF (1.10 ml) were heated to 50°C overnight to yield a clear colorless solution. For MAPbCl$_3$, PbCl$_2$ (280 mg, 1.01 mmol), MACI (76 mg, 1.13 mmol), and DMSO (500 μl) were heated to 60°C to yield a clear colorless solution. For CsPbBr$_3$, stirring a mixture of PbBr$_2$ (367 mg, 1.00 mmol), CsBr (215 mg, 1.01 mmol), and DMSO (2.4 ml) overnight at 70°C resulted in a clear colorless solution. Iodide-bromide– and bromide-chloride–containing precursors were prepared from single-halide solutions by mixing at an 80:20 volume ratio.

**Nanoporous silicon**

Two types of boron-doped p-type silicon wafers with thickness of 0.5 mm and <100> orientation were used: either “low-doped,” with $R_0 = 8$ to 20 ohm cm, or “highly-doped,” with $R_0 = 0.01$ ohm cm. The wafers were polished on one side, with an alkali-etched backside. The Si wafers were cut into 1" × 1” squares, cleaned by ultrasonication sequentially in 2% solution of chemical detergent Hellmanex III, deionized water, acetone, and 2-propanol, followed by the RCA (Radio Corporation of America) standard cleaning steps (59). Next, 250-nm aluminum contacts were evaporated onto the alkali-etched backside. After the deposition of the Al, the samples were annealed in N$_2$ atmosphere for 20 min at 450°C to ensure an ohmic Al/p Si contact. The polished surface of the substrate was nanostructured by anodization sequentially in 2% solution of chemical detergent Hellmanex III, deionized water, acetone, and 2-propanol, followed by the RCA (Radio Corporation of America) standard cleaning steps (59). Nanoporous perovskite nanocrystal LEDs

Patterned FTO-coated glass slides (Xin Yan Technology Ltd.; 1" × 1" with a centered, 1.35-cm-wide and 2.5-cm-long stripe of FTO with a sheet resistance of 15 ohms per square) were polished with a titanium- and silicon oxide–containing polishing paste to improve surface qualities. The FTO-coated glass slides were further cleaned using sequential ultrasonication as described for the npAAO preparation and subsequently treated with oxygen plasma (50 W for 5 min). Layers of titanum (15 nm) and aluminum (40 nm) were evaporated sequentially on top of the FTO in the same thermal evaporation system without breaking vacuum, with deposition rates of 0.1 and 1 nm s$^{-1}$ at a base pressure of 1 × 10$^{-6}$ mbar. Anodization of the double layer was performed as described above. This one-pot anodization protocol resulted in an optically transparent npAAO scaffold atop a compact titania film. This functional oxide double-layer architecture served both as electron injection contact and as insulating nanoscale template for the formation of conjugated perovskite nanocrystals. After rinsing with 18-megohm water and drying, samples were treated with oxygen plasma (50 W for 5 min). The perovskite precursor solutions (parent solution of MAPbI$_3$ diluted in a volume ratio of 1:22 with DMF or parent solution of MAPbI$_3$ diluted in a volume ratio of 1:15 with DMF) were deposited by spin-coating at 2400 rpm for 7 s. These recipes allowed filling of the 60-nm high-porous matrix without the formation of bulk perovskite layers, resulting in electrically addressable conjugated nanocrystals. The samples were annealed for 30 min at 115°C in ambient atmosphere. Poly[9,9-dioctylfluorenyl-2,7-diyl] end-capped with N,N-bis(4-methylphenyl)-aniline (F8, purchased from ADS; 0.5 wt %), dissolved in chlorobenzene, was spin-coated at 3000 rpm until dry-yielding a hole-transporting polymer layer. Molybdenum(VI) oxide (20 nm) and silver (100 nm), thermally deposited at rates of 0.03 and 1 nm s$^{-1}$ through a metal shadow mask at a base pressure of ~1 × 10$^{-6}$ mbar, completed the device.

**High-energy x-ray diffraction**

The measurements were performed at the high-energy beamline (P07) at PETRA III at DESY (Deutsches Elektronen-Synchrotron). The 30-μm cm$^{-2}$ npSi/ncMAPbI$_3$ sample was measured with an x-ray beam with an energy of 98.5 keV, which was focused down to a spot.
of 5 μm × 50 μm (vertical × horizontal FWHM) at the sample position using Al compound refractive lenses. For all other samples, the respective values were 80.0 keV and 2 μm × 30 μm. The diffracted intensity was recorded 2000 mm behind the sample by a PerkinElmer XRD 1621 flat panel detector. To distinguish clearly between the signal of the perovskite and the background resulting from the substrate, a reference npSi sample without perovskite was measured for each beam configuration. For data processing, Igor Pro (WaveMetrics), including the “Nika” package (60), and OriginPro (OriginLab) were used (see the Supplementary Materials for details).

Small-angle x-ray diffraction

The samples were measured in transmission with the surface perpendicular to a 20.0-keV x-ray beam at beamline P08 at PETRA III at DESY. The scattered intensity was detected by a PerkinElmer XRD 1621 flat panel detector at a distance of 2440 mm behind the sample. For data analysis, the “Nika” package (60) for Igor Pro (WaveMetrics) and SASfit (61) were used.

Scanning transmission electron microscopy

The npSi specimens were prepared by mechanical exfoliation from the porous areas of the sample on a holey carbon TEM grid. The npAAO specimens were prepared by FIB milling (1540 CrossBeam SEM, Zeiss). A thin gold layer was sputtered onto the specimen before milling. TEM lamellae were prepared by standard FIB cutting, lifting out, and transferring to a TEM grid, followed by a final thinning to about 100 nm with an ion energy of 5 keV to minimize preparation artifacts. STEM was performed in BF and HAADF modes, sensitive to the z-contrast of the Pb-rich regions. Line and mapping analyses were carried out using EDX. All specimens were investigated with a JEOL JEM-2200FS TEM under STEM mode operated at 200 kV, and an Oxford SDD X-MaxN (80 mm²) EDX system.

Sample characterization

Surface SEM measurements were made using the Zeiss 1540 XB CrossBeam SEM. Optical microscopy images were recorded using a Nikon Eclipse LV100ND microscope with up to ×400 magnification and a PL filter cube accessory. PL spectra were recorded on a photomultiplier tube–equipped double-grating input and output fluorometer (Photon Technology International). EL measurements were performed using a Shamrock spectrometer (SR-303i-A), equipped with an intensified charge-coupled device camera [Andor iStar DH320T-18U-73 (gate step, 2.5 ns; gate width, 2.5 ns)]. The samples were kept under vacuum during the measurement. Corresponding shorter-lived perovskite nanocrystals in 5–mA cm⁻² npSi templates were investigated using a superconducting single photon detector (SSPD; Scontel Superconducting Nanotechnology) together with a time-correlated single-photon counting system (PicoHarp 300 by PicoQuant). The time resolution of the SSPD system is about 300 ps. Samples were excited by a pulsed diode laser (405 nm) delivering ~1 ns pulses (FWHM) at repetition rates of 1 MHz and pulse energies of approximately 5 pJ. A microscope objective was used to focus the laser onto a spot with a 10-μm diameter on the sample surface. The sample emission was collected using the same microscope objective, and the photons were guided through a single-mode fiber to the SSPD. A long-pass filter was applied to block the excitation before entering the fiber connected to the SSPD.

PL quantum efficiency

Samples were prepared as described before, using a 150-nm-thick layer of npAAO on glass. Bulk references were also prepared on glass. Several samples were prepared for each of the systems with varying concentrations of precursor solutions ranging from 0.06 to 0.1 M. The PL quantum efficiency was measured using a method previously described in literature (62). The measurement was performed inside an integrating sphere in a fluorometer (Photon Technology International), and the excitation wavelength was 405 nm with an illumination intensity of approximately 0.4 mW cm⁻².

PL stability measurements

Samples were prepared with 150 nm of npAAO on glass and 0.08 M solution of CsPbBr₃ or MAPbBr₃. Samples were placed in a fluorometer (Photon Technology International), and the spectra were recorded for about 28 hours. Peak intensity was used for the data evaluation. Peak wavelength was monitored, and it showed no variation throughout the duration of the measurement. Encapsulated samples of perovskite nanocrystals in npAAO were sealed with UV curable epoxy (Ozalla E131) and glass slides.

Time-resolved PL lifetime measurements

Bulk MAPbI₃, MAPbBr₃, and CsPbBr₃ films were measured using an yttrium-aluminum-garnet–Nd laser (Spotlight Compact 100) emitting at 355 or 532 nm with a pulse length of ~10 ns and an energy of 50 μJ cm⁻² in both cases. The spot size was 5 mm in diameter. Signal detection was performed with a Shamrock spectrometer (SR-303i-A), equipped with an intensified charge-coupled device camera [Andor iStar DH320T-18U-73 (gate step, 2.5 ns; gate width, 2.5 ns)]. The samples were kept under vacuum during the measurement. Corresponding shorter-lived perovskite nanocrystals in 5–mA cm⁻² npSi templates were investigated using a superconducting single photon detector (SSPD; Scontel Superconducting Nanotechnology) together with a time-correlated single-photon counting system (PicoHarp 300 by PicoQuant).

SUPPLEMENTARY MATERIALS

Supplementary material for this article is available at http://advances.sciencemag.org/cgi/content/full/3/8/e1700738/DC1

fig. S1. Bandgap tuning via size effects and halide compositional stoichiometry in npSi and npAAO.
fig. S2. PL of native npSi and MAPbI₃ nanocrystals in npSi.
fig. S3. Fine-tuning of the bandgap in npSi via variation of pore size.
fig. S4. Time-resolved PL lifetime.
fig. S5. Structural characterization of MAPbBr₃ nanocrystals in npAAO.
fig. S6. Wide-angle x-ray scattering (WAXS) study of MAPbI₃ nanocrystals in 30-nm cm⁻² npSi.
fig. S7. RXS study of MAPbI₃ nanocrystals in 15–mA cm⁻² npSi.
fig. S8. Measurement of superconducting quantum interference devices (SQUIDs)–npSi:
fig. S9. Surface SEM of npAAO on compact TiO₂:

REFERENCES AND NOTES


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Confining metal-halide perovskites in nanoporous thin films

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